

RQK0204TGDQA

Silicon N Channel MOS FET
Power Switching

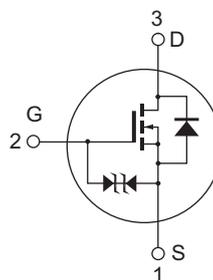
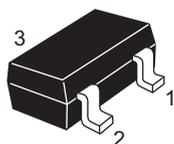
R07DS0304EJ0500
Rev.5.00
Jan 10, 2014

Features

- Low on-resistance
 $R_{DS(on)} = 100 \text{ m}\Omega$ typ ($V_{GS} = 4.5 \text{ V}$, $I_D = 1.2 \text{ A}$)
- Low drive current
- High speed switching
- 2.5 V gate drive

Outline

RENESAS Package code: PLSP0003ZB-A
(Package name: MPAK)



1. Source
2. Gate
3. Drain

Note: Marking is "TG".

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	20	V
Gate to source voltage	V_{GSS}	± 12	V
Drain current	I_D	2.3	A
Drain peak current	$I_{D(pulse)}$ ^{Note1}	8.0	A
Body - drain diode reverse drain current	I_{DR}	2.3	A
Channel dissipation	P_{ch} ^{Note2}	0.8	W
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

2. When using the glass epoxy board (FR-4: 40 x 40 x 1 mm)

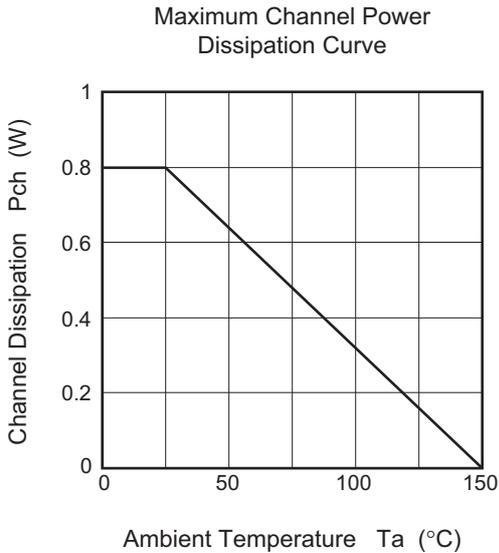
Electrical Characteristics

(Ta = 25°C)

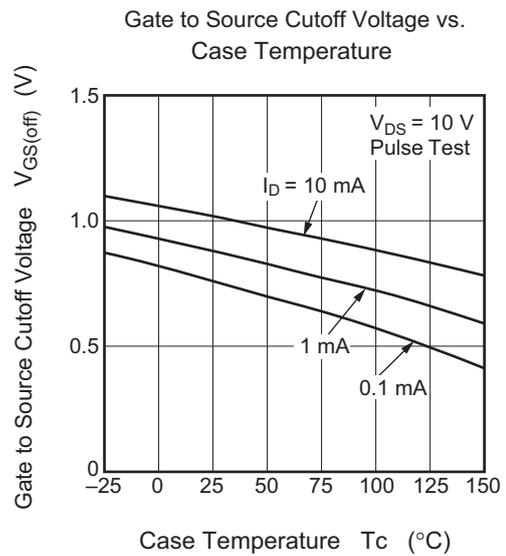
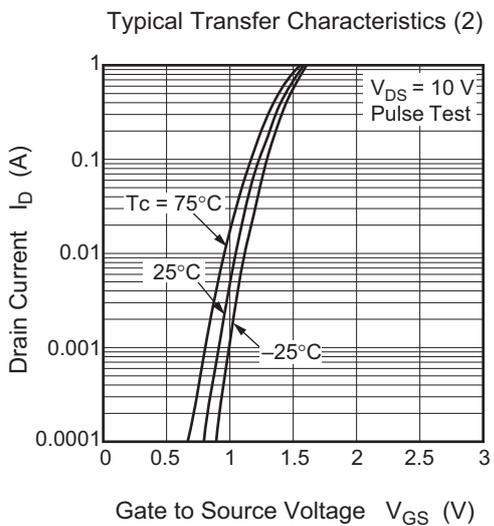
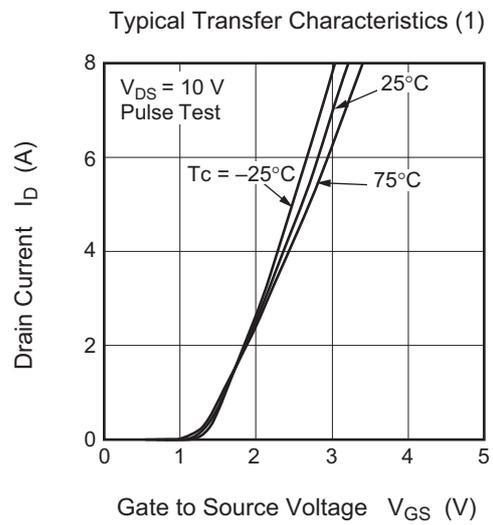
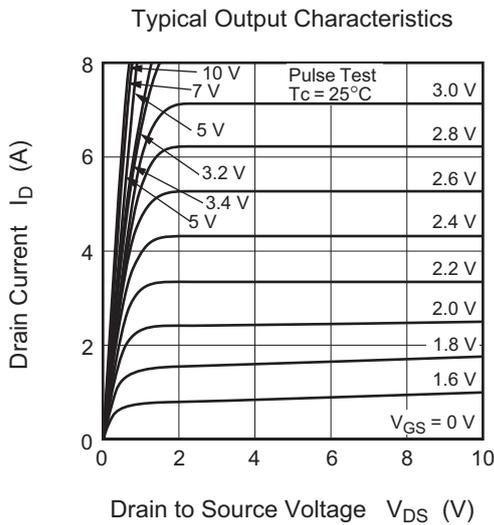
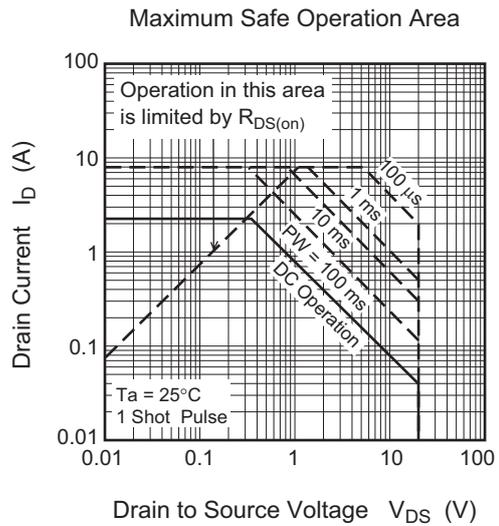
Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	20	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 12	—	—	V	$I_G = \pm 100 \text{ }\mu\text{A}$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 10 \text{ V}$, $V_{DS} = 0$
Drain to source leak current	I_{DSS}	—	—	1	μA	$V_{DS} = 20 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	0.4	—	1.4	V	$V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$
Drain to source on state resistance	$R_{DS(on)}$	—	100	130	m Ω	$I_D = 1.2 \text{ A}$, $V_{GS} = 4.5 \text{ V}$ ^{Note3}
	$R_{DS(on)}$	—	146	204	m Ω	$I_D = 1.2 \text{ A}$, $V_{GS} = 2.5 \text{ V}$ ^{Note3}
Forward transfer admittance	$ y_{fs} $	1.5	3.0	—	S	$I_D = 1.2 \text{ A}$, $V_{DS} = 10 \text{ V}$ ^{Note3}
Input capacitance	C_{iss}	—	127	—	pF	$V_{DS} = 10 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	33	—	pF	
Reverse transfer capacitance	C_{rss}	—	14	—	pF	
Turn - on delay time	$t_{d(on)}$	—	11	—	ns	$I_D = 1.2 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 8.3 \text{ }\Omega$ $R_g = 4.7 \text{ }\Omega$
Rise time	t_r	—	28	—	ns	
Turn - off delay time	$t_{d(off)}$	—	24	—	ns	
Fall time	t_f	—	7	—	ns	
Total gate charge	Q_g	—	1.5	—	nC	$V_{DD} = 10 \text{ V}$ $V_{GS} = 5 \text{ V}$ $I_D = 2.3 \text{ A}$
Gate to source charge	Q_{gs}	—	0.3	—	nC	
Gate to drain charge	Q_{gd}	—	0.4	—	nC	
Body - drain diode forward voltage	V_{DF}	—	0.85	1.1	V	$I_F = 2.3 \text{ A}$, $V_{GS} = 0$ ^{Note3}

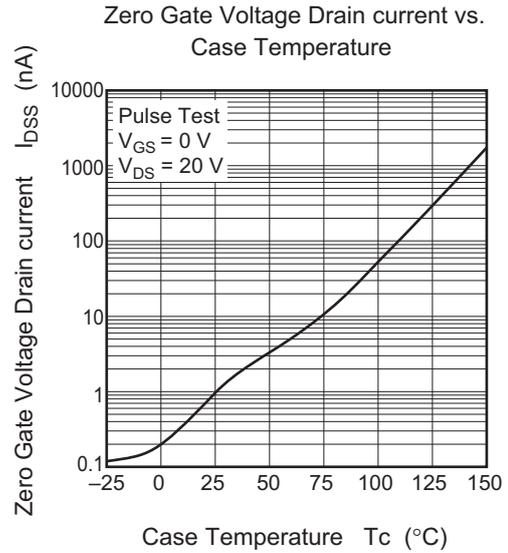
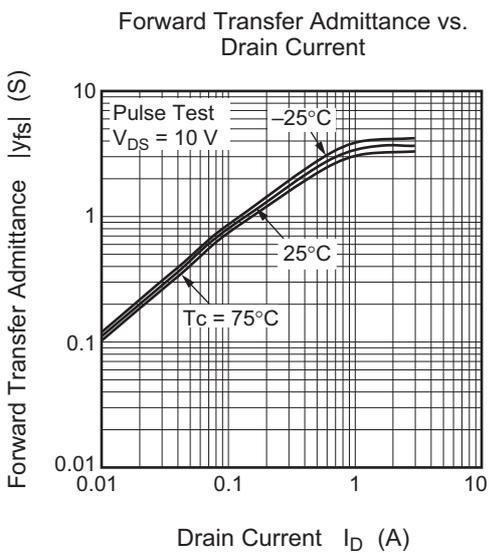
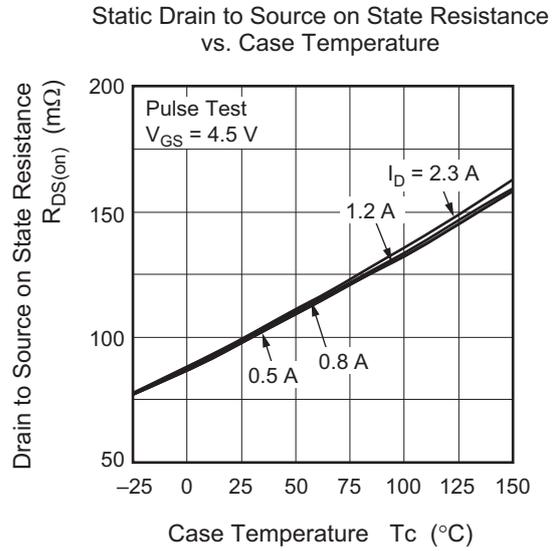
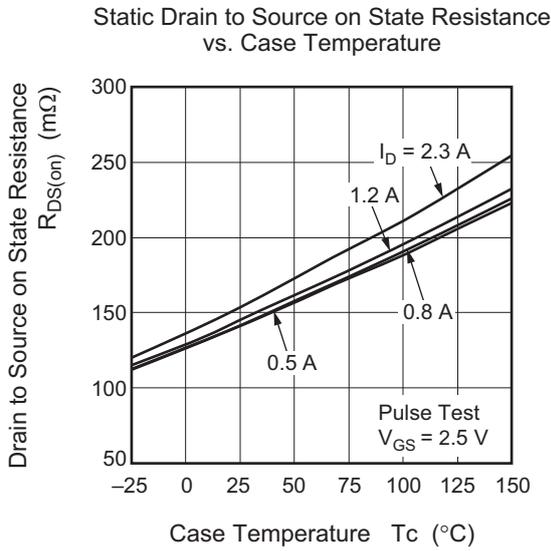
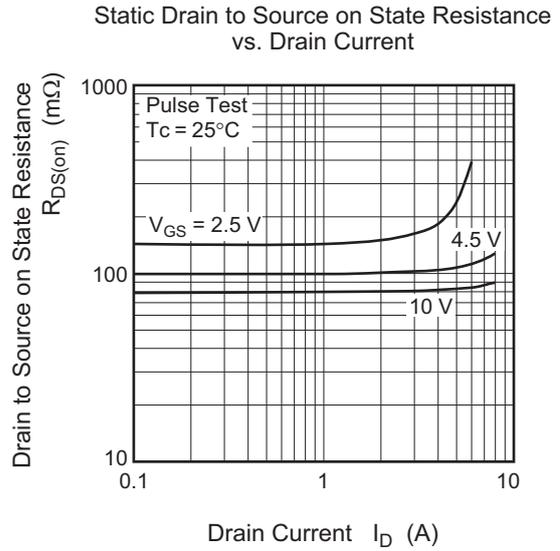
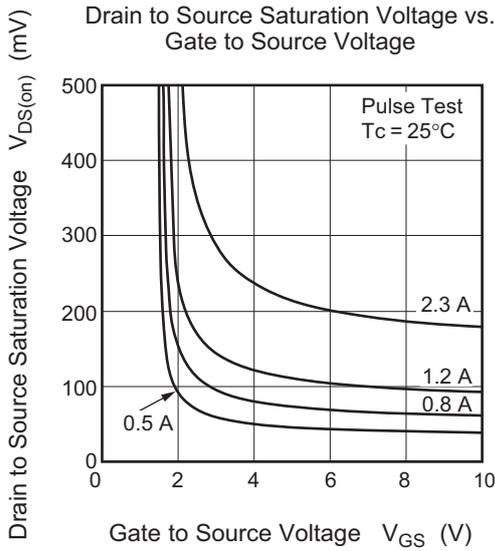
Notes: 3. Pulse test

Main Characteristics

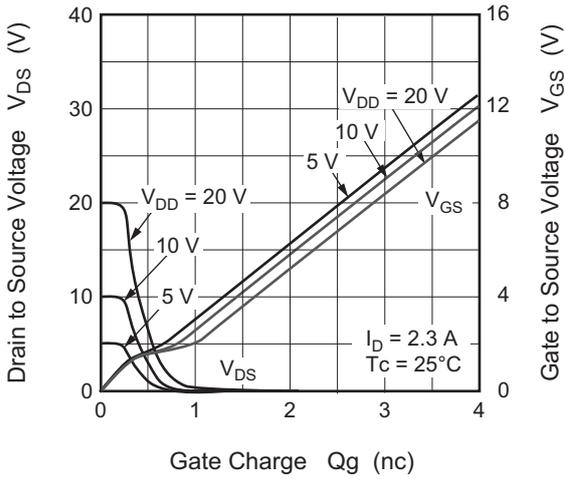


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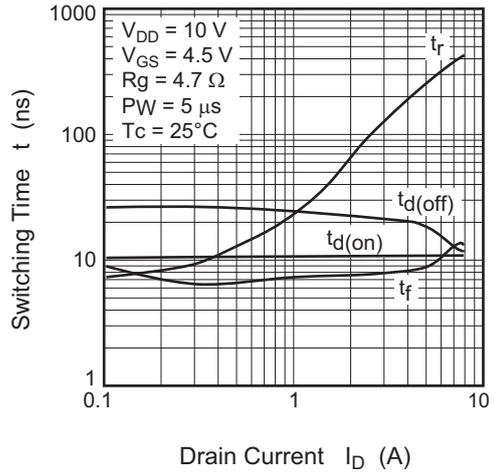




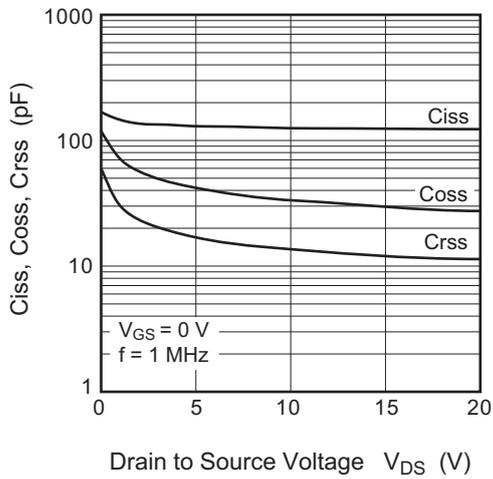
Dynamic Input Characteristics



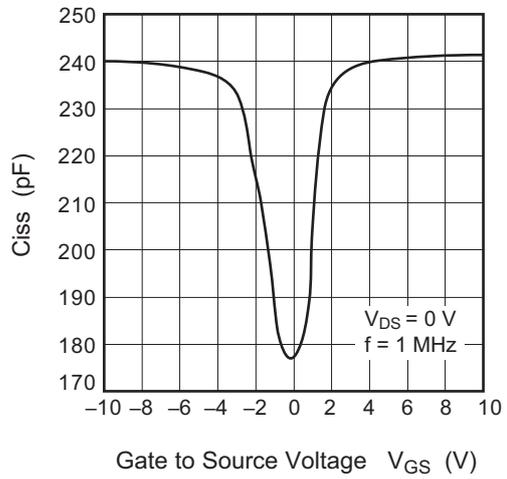
Switching Characteristics



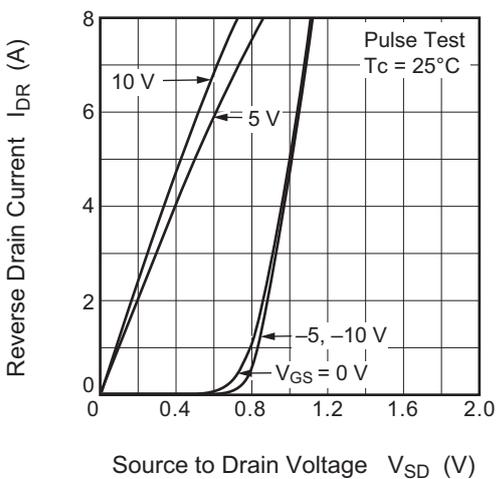
Typical Capacitance vs. Drain to Source Voltage



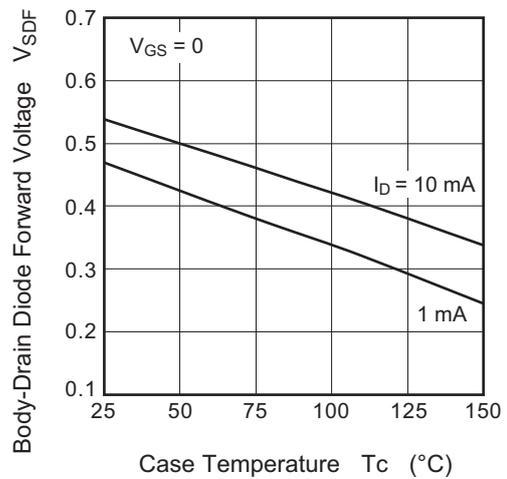
Input Capacitance vs. Gate to Source Voltage



Reverse Drain Current vs. Source to Drain Voltage

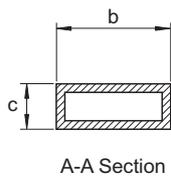
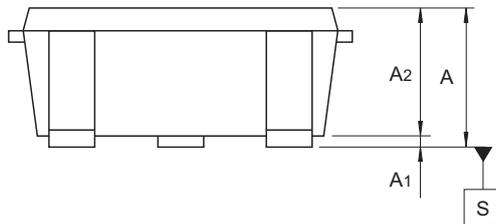
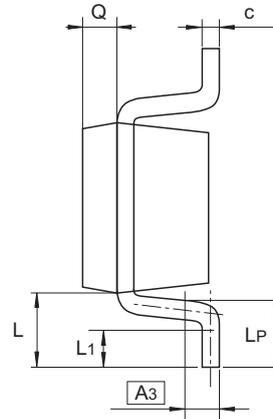
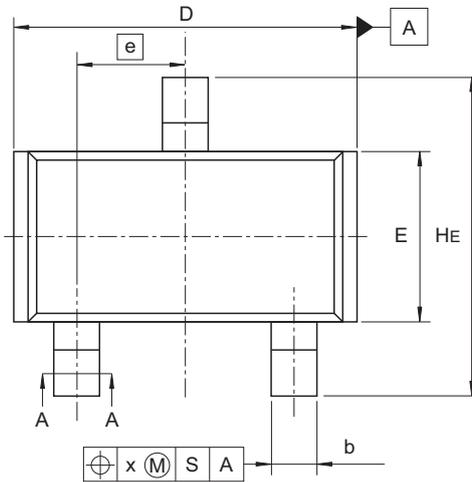


Body-Drain Diode Forward Voltage vs. Case Temperature



Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-59A	PLSP0003ZB-A	MPAK(T) / MPAK(T)V	0.011



Reference Symbol	Dimensions in millimeters		
	Min	Nom	Max
A	1.0	—	1.3
A1	0	—	0.1
A2	1.0	1.1	1.2
A3	—	0.25	—
b	0.35	0.4	0.5
c	0.1	0.16	0.26
D	2.7	—	3.1
E	1.35	1.5	1.65
e	—	0.95	—
HE	2.2	2.8	3.0
L	0.35	—	0.75
L1	0.15	—	0.55
LP	0.25	—	0.65
x	—	—	0.05
Q	—	0.3	—

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Ordering Information

Orderable Part Number	Quantity	Shipping Container
RQK0204TGDQATL-H	3000 pcs.	φ178 mm reel, 8 mm Emboss taping

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